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DMG96401

Silicon NPN epitaxial planar type (Tr1) Silicon PNP epitaxial planar type (Tr2)

For digital circuits
DMG56401 in SSMini6 type package

■ Features

- ullet Low collector-emitter saturation voltage $V_{\text{CE(sat)}}$
- Halogen-free / RoHS compliant
 (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)

■ Marking Symbol: E6

■ Basic Part Number

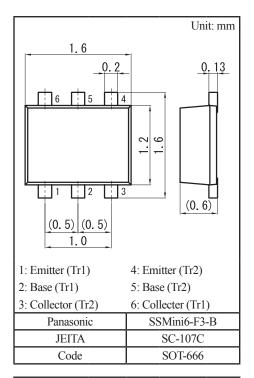
DRC2114E + DRA2114E (Individual)

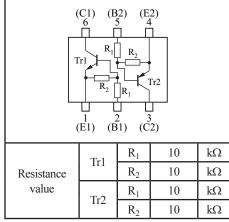
■ Packaging

DMG964010R Embossed type (Thermo-compression sealing): 8 000 pcs / reel (standard)

■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter | | Symbol | Rating | Unit | |
|-----------|---------------------------------------|------------------|-------------|------|--|
| Tr1 | Collector-base voltage (Emitter open) | V _{CBO} | 50 | V | |
| | Collector-emitter voltage (Base open) | V _{CEO} | 50 | V | |
| | Collector current | I_{C} | 100 | mA | |
| Tr2 | Collector-base voltage (Emitter open) | V _{CBO} | -50 | V | |
| | Collector-emitter voltage (Base open) | V _{CEO} | -50 | V | |
| | Collector current | I_{C} | -100 | mA | |
| Overall | Total power dissipation | P_{T} | 125 | mW | |
| | Junction temperature | T _j | 150 | °C | |
| | Operating ambient temperature | T _{opr} | -40 to +85 | °C | |
| | Storage temperature | T _{stg} | -55 to +150 | °C | |





■ Electrical Characteristics $T_a = 25$ °C±3°C

• Tr1

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|----------------------|--|------|-----|------|------|
| Collector-base voltage (Emitter open) | V_{CBO} | $I_C = 10 \mu A, I_E = 0$ | 50 | | | V |
| Collector-emitter voltage (Base open) | V _{CEO} | $I_C = 2 \text{ mA}, I_B = 0$ | 50 | | | V |
| Collector-base cutoff current (Emitter open) | I_{CBO} | $V_{\rm CB} = 50 \text{ V}, I_{\rm E} = 0$ | | | 0.1 | μΑ |
| Collector-emitter cutoff current (Base open) | I _{CEO} | $V_{CE} = 50 \text{ V}, I_{B} = 0$ | | | 0.5 | μΑ |
| Emitter-base cutoff current (Collector open) | I_{EBO} | $V_{EB} = 6 \text{ V}, I_C = 0$ | | | 0.5 | mA |
| Forward current transfer ratio | h_{FE} | $V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}$ | 35 | | | _ |
| Collector-emitter saturation voltage | V _{CE(sat)} | $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$ | | | 0.25 | V |
| Input voltage (ON) | V _{I(on)} | $V_{CE} = 0.2 \text{ V}, I_{C} = 5 \text{ mA}$ | 2.1 | | | V |
| Input voltage (OFF) | V _{I(off)} | $V_{CE} = 5 \text{ V}, I_{C} = 100 \mu\text{A}$ | | | 0.8 | V |
| Input resistance | R_1 | | -30% | 10 | +30% | kΩ |
| Resistance ratio | R_1/R_2 | | 0.8 | 1.0 | 1.2 | |

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

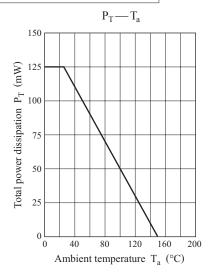
• Tr2

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|----------------------|---|------|-----|-------|------|
| Collector-base voltage (Emitter open) | V_{CBO} | $I_{\rm C} = -10 \mu A, I_{\rm E} = 0$ | -50 | | | V |
| Collector-emitter voltage (Base open) | V _{CEO} | $I_{\rm C} = -2 \text{ mA}, I_{\rm B} = 0$ | -50 | | | V |
| Collector-base cutoff current (Emitter open) | I_{CBO} | $V_{\rm CB} = -50 \text{ V}, I_{\rm E} = 0$ | | | -0.1 | μΑ |
| Collector-emitter cutoff current (Base open) | I_{CEO} | $V_{CE} = -50 \text{ V}, I_{B} = 0$ | | | -0.5 | μΑ |
| Emitter-base cutoff current (Collector open) | I _{EBO} | $V_{EB} = -6 \text{ V}, I_C = 0$ | | | -0.5 | mA |
| Forward current transfer ratio | h_{FE} | $V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$ | 35 | | | _ |
| Collector-emitter saturation voltage | V _{CE(sat)} | $I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$ | | | -0.25 | V |
| Input voltage (ON) | V _{I(on)} | $V_{CE} = -0.2 \text{ V}, I_{C} = -5 \text{ mA}$ | -2.1 | | | V |
| Input voltage (OFF) | V _{I(off)} | $V_{CE} = -5 \text{ V}, I_{C} = -100 \mu\text{A}$ | | | -0.8 | V |
| Input resistance | R_1 | | -30% | 10 | +30% | kΩ |
| Resistance ratio | R_1/R_2 | | 0.8 | 1.0 | 1.2 | _ |

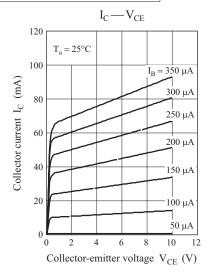
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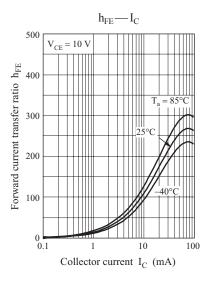
Ver. FED 2

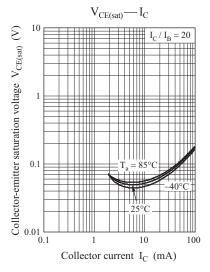
Common characteristics chart

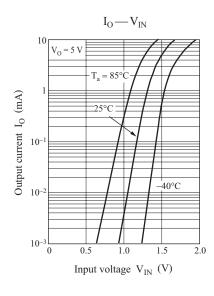


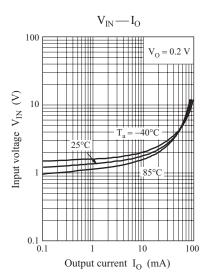
Characteristics charts of Tr1



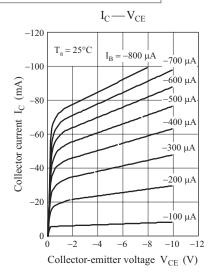


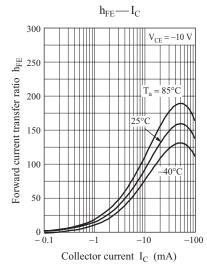


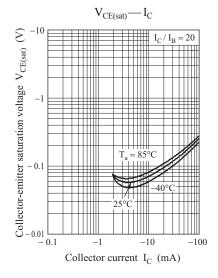


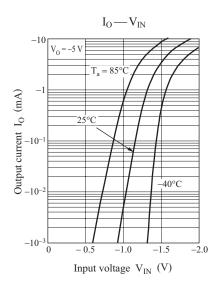


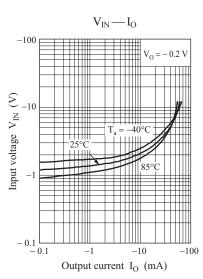
Characteristics charts of Tr2







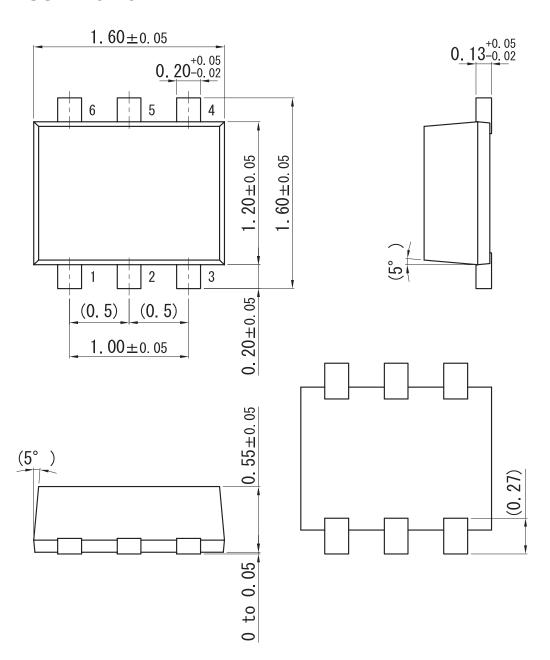




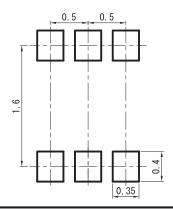
Ver. FED 4

SSMini6-F3-B

Unit: mm



■ Land Pattern (Reference) (Unit: mm)



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